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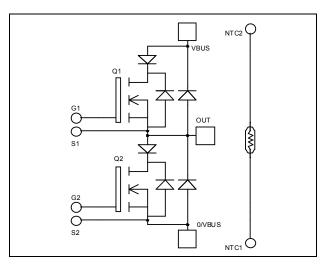
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Phase leg Series & parallel diodes MOSFET Power Module



VBUS OUT VBUS OUT S1 S2 G1 G2

APTM100A23STG

 $V_{DSS} = 1000V$ $R_{DSon} = 230 m\Omega \text{ typ}$ (a) $Tj = 25^{\circ}C$ $I_D = 36A$ (a) $Tc = 25^{\circ}C$

Application

- Motor control
 - Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - Lead frames for power connections
- Internal thermistor for temperature monitoring
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

All ratings (a) $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage		1000	V
т	Continuous Drain Current	$T_c = 25^{\circ}C$	36	
ID	I _D Continuous Drain Current	$T_c = 80^{\circ}C$	27	Α
I _{DM}	Pulsed Drain current		144	
V _{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		270	mΩ
PD	Maximum Power Dissipation	$T_c = 25^{\circ}C$	694	W
I _{AR}	Avalanche current (repetitive and non repetitive)		18	А
E _{AR}	Repetitive Avalanche Energy		50	m I
E _{AS}	Single Pulse Avalanche Energy		2500	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			200	
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125^{\circ}C$			1000	μA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 18A$			230	270	mΩ
V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 5mA$		3		5	V
I _{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	V			±150	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Тур	Max	Unit
C _{iss}	Input Capacitance	$V_{GS} = 0V$		8700		
Coss	Output Capacitance	$V_{\rm DS} = 25 V$		1430		pF
C _{rss}	Reverse Transfer Capacitance	f = 1MHz		240		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		308		
Q _{gs}	Gate – Source Charge	$V_{Bus} = 500V$		52		nC
Q_{gd}	Gate – Drain Charge	$I_D = 36A$		194		
T _{d(on)}	Turn-on Delay Time	Inductive switching @ $125^{\circ}C$ $V_{GS} = 15V$ $V_{Bus} = 667V$ $I_D = 36A$		10		
Tr	Rise Time			12		
T _{d(off)}	Turn-off Delay Time			121		ns
$T_{\rm f}$	Fall Time	$R_G = 2.5\Omega$		35		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		1278		T
E _{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 36A, R_G = 2.5\Omega$		760		μJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		2092		т
$\mathrm{E}_{\mathrm{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 36A, R_G = 2.5\Omega$		902		μJ
R _{thJC}	Junction to Case Thermal Resistance				0.18	°C/W

Series diode ratings and characteristics

Symbol	Characteristic Test Conditions		Min	Тур	Max	Unit	
V _{RRM}	Maximum Peak Repetitive Reverse Vol	ltage		1000			V
I _{RM}	Maximum Reverse Leakage Current	$V_{R} = 1000V$				500	μA
I _F	DC Forward Current		$T_c = 65^{\circ}C$		90		А
		$I_F = 90A$			1.9	2.3	
V _F	Diode Forward Voltage	$I_{\rm F} = 180 {\rm A}$			2.2		V
		$I_F = 90A$	$T_{j} = 125^{\circ}C$		1.7		
+	Poverse Persylary Time		$T_j = 25^{\circ}C$		290		20
t _{rr}		$I_{\rm F} = 90 \text{A}$ $V_{\rm R} = 667 \text{V}$	$T_j = 125^{\circ}C$		390		ns
Q _{rr}		$di/dt = 400 A/\mu s$	$T_j = 25^{\circ}C$		2010		nC
Qrr			$T_{j} = 125^{\circ}C$		7050		пс
R _{thJC}	Junction to Case Thermal Resistance					0.45	°C/W



Parallel diode ratings and characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Vol	tage		1000			V
I _{RM}	Maximum Reverse Leakage Current	V _R =1000V				150	μA
$I_{\rm F}$	DC Forward Current		$T_c = 80^{\circ}C$		80		Α
		$I_F = 80A$			2.5	3.5	
$V_{\rm F}$	Diode Forward Voltage	$I_{\rm F} = 140 {\rm A}$			3.1		V
		$I_F = 80A$	$T_{j} = 125^{\circ}C$		2		
+			$T_j = 25^{\circ}C$		250		
ι _{rr}		$I_{\rm F} = 80 \text{A}$ $V_{\rm R} = 667 \text{V}$	$T_j = 125^{\circ}C$		315		ns
0	Reverse Recovery Charge	$di/dt = 400 \text{A}/\mu\text{s}$	$T_j = 25^{\circ}C$		830		
Q _{rr}		•	$T_{j} = 125^{\circ}C$		3300		nC
R _{thJC}	Junction to Case Thermal Resistance					0.65	°C/W

Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
VISOL	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
TJ	Operating junction temperature range			-40		150	
T _{STG}	Storage Temperature Range			-40		125	°C
T _C	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M5	2.5		4.7	N.m
Wt	Package Weight					160	g

Temperature sensor NTC (see application note APT0406 on www.microsemi.com).

Symbol	Characteristic		Min	Тур	Max	Unit
R ₂₅	Resistance @ 25°C	25°C		50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B _{25/85}	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta B/B$		T _C =100°C		4		%

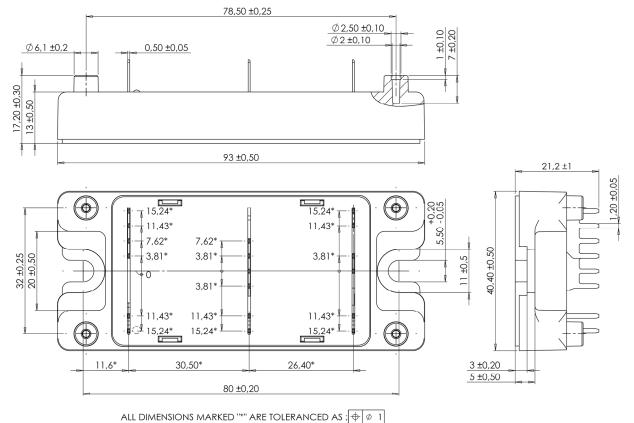
$$R_{T} = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Therming R_T: Therming R_T: Thermine R_{T}: Thermine R_{T}: Thermine R_{T}: Thermine R_{T}: Thermine R_

Thermistor temperature : Thermistor value at T

APTM100A23STG - Rev 5 October, 2013



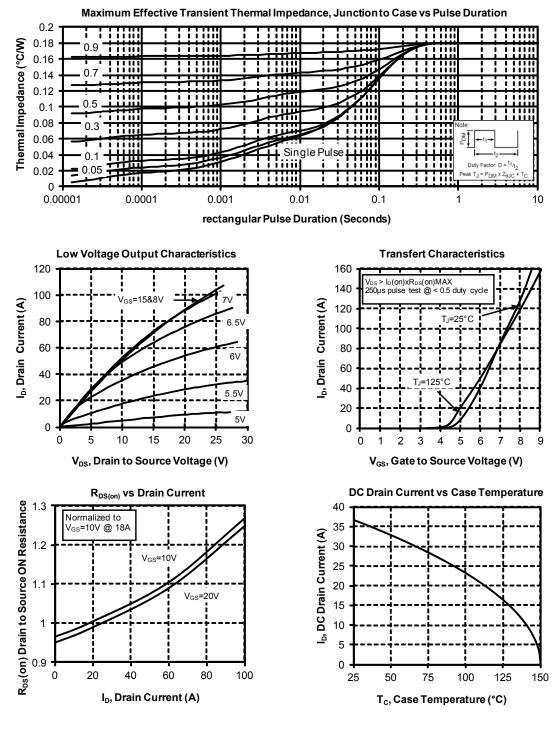
SP4 Package outline (dimensions in mm)



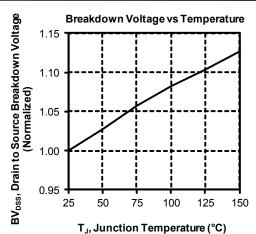
See application note APT0501 - Mounting Instructions for SP4 Power Modules on www.microsemi.com



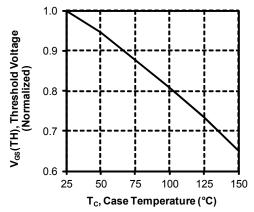
Typical Performance Curve



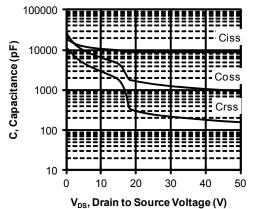


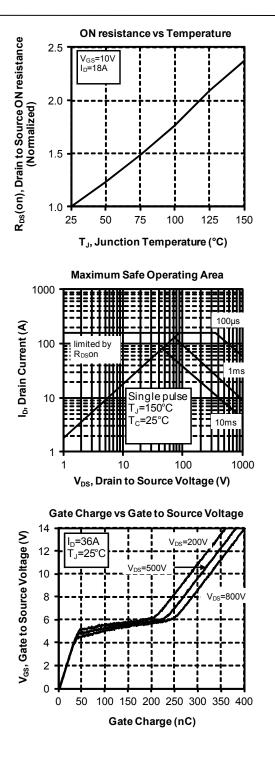




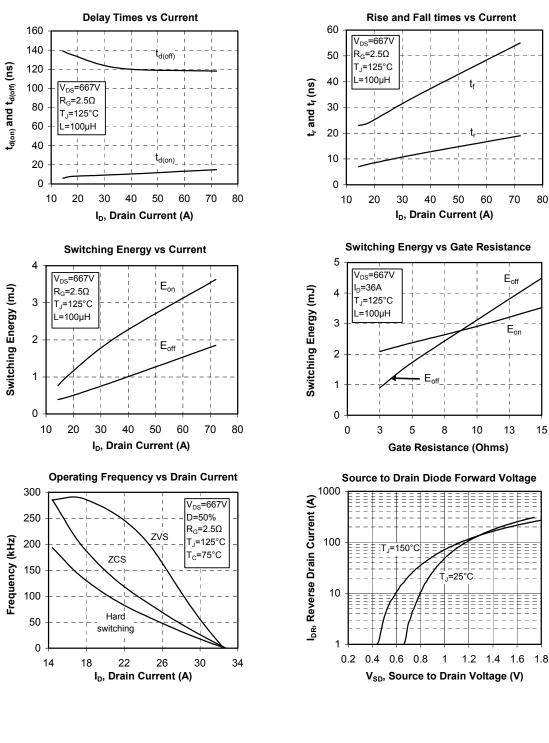














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